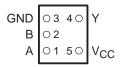
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- Available in the Texas Instruments
   NanoStar™ and NanoFree™ Packages
- Optimized for 1.8-V Operation and Is 3.6-V I/O Tolerant to Support Mixed-Mode Signal Operation
- I<sub>off</sub> Supports Partial-Power-Down Mode Operation
- Sub 1-V Operable
- Max t<sub>pd</sub> of 2.4 ns at 1.8 V
- Low Power Consumption, 10-μA Max I<sub>CC</sub>
- ±8-mA Output Drive at 1.8 V
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)
  - 1000-V Charged-Device Model (C101)

# DBV OR DCK PACKAGE (TOP VIEW) A 1 5 VCC B 2 GND 3 4 Y

YEA, YEP, YZA, OR YZP PACKAGE (BOTTOM VIEW)



#### description/ordering information

This single 2-input positive-AND gate is operational at 0.8-V to 2.7-V  $V_{CC}$ , but is designed specifically for 1.65-V to 1.95-V  $V_{CC}$  operation.

The SN74AUC1G08 performs the Boolean function  $Y = A \bullet B$  or  $Y = \overline{A} + \overline{B}$  in positive logic.

NanoStar™ and NanoFree™ package technology is a major breakthrough in IC packaging concepts, using the die as the package.

This device is fully specified for partial-power-down applications using I<sub>off</sub>. The I<sub>off</sub> circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

#### **ORDERING INFORMATION**

TA	PACKAGE <sup>†</sup>	ORDERABLE PART NUMBER	TOP-SIDE MARKING <sup>‡</sup>	
	NanoStar™ WCSP (DSBGA) – YEA		SN74AUC1G08YEAR	
–40°C to 85°C	NanoFree™ WCSP (DSBGA) – YZA (Pb-free)	Tone and real	SN74AUC1G08YZAR	ue.
	NanoStar™ – WCSP (DSBGA) 0.23-mm Large Bump – YEP	Tape and reel	SN74AUC1G08YEPR	UE_
	NanoFree™ – WCSP (DSBGA) 0.23-mm Large Bump – YZP (Pb-free)		SN74AUC1G08YZPR	
	SOT (SOT-23) – DBV	Tape and reel	SN74AUC1G08DBVR	U08_
	SOT (SC-70) – DCK	Tape and reel	SN74AUC1G08DCKR	UE_

<sup>†</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

DBV/DCK: The actual top-side marking has one additional character that designates the assembly/test site. YEA/YZA, YEP/YZP: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following character to designate the assembly/test site.



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#### **FUNCTION TABLE**

INPU	JTS	OUTPUT
Α	В	Υ
Н	Н	Н
L	Χ	L
Х	L	L

#### logic diagram (positive logic)



#### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, $V_{CC}$	
Voltage range applied to any output in the high-impedance or power-off state, V <sub>O</sub>	0.5.V.to.3.6.V
(see Note 1)	
Input clamp current, I <sub>IK</sub> (V <sub>I</sub> < 0)	
Output clamp current, I <sub>OK</sub> (V <sub>O</sub> < 0)	–50 mA
Continuous output current, I <sub>O</sub>	±20 mA
Continuous current through V <sub>CC</sub> or GND	±100 mA
Package thermal impedance, θ <sub>JA</sub> (see Note 2): DBV package	206°C/W
DCK package	
YEA/YZA package	
YEP/YZP package	132°C/W
Storage temperature range, T <sub>stq</sub>	–65°C to 150°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

2. The package thermal impedance is calculated in accordance with JESD 51-7.



#### recommended operating conditions (see Note 3)

			MIN	MAX	UNIT
Vcc	Supply voltage		0.8	2.7	V
Vu . High lovel input volte	High-level input voltage	$V_{CC} = 0.8 \text{ V to } 1.95 \text{ V}$	0.65 × V <sub>CC</sub>		V
VIH	7IH High-lever input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.7		V
\/	Low-level input voltage	$V_{CC} = 0.8 \text{ V to } 1.95 \text{ V}$		0.35 × V <sub>CC</sub>	V
VIL	Low-level input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		0.7	V
٧ <sub>I</sub>	Input voltage		0	3.6	V
Vo	Output voltage		0	Vcc	V
		V <sub>CC</sub> = 0.8 V		-0.7	mA
	High-level output current	V <sub>CC</sub> = 1.1 V		-3	
IOH		V <sub>CC</sub> = 1.4 V		-5	
		$V_{CC} = 1.65 \text{ V}$		-8	
		V <sub>CC</sub> = 2.3 V		-9	
		V <sub>CC</sub> = 0.8 V		0.7	
		V <sub>CC</sub> = 1.1 V		3	
loL	Low-level output current	V <sub>CC</sub> = 1.4 V		5	mA
		V <sub>CC</sub> = 1.65 V		8	
		V <sub>CC</sub> = 2.3 V		9	
Δt/Δν	Input transition rise or fell rate	V <sub>CC</sub> = 0.8 V to 1.95 V		20	ns/V
ΔΨΔΨ	Input transition rise or fall rate	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		10	115/ V
TA	Operating free-air temperature		-40	85	°C

NOTE 3: All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

# electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

Р	ARAMETER	TEST CONDITIONS	Vcc	MIN	TYP <sup>†</sup>	MAX	UNIT
		I <sub>OH</sub> = -100 μA	0.8 V to 2.7 V	V <sub>CC</sub> -0.1			
		$I_{OH} = -0.7 \text{ mA}$	0.8 V		0.55		
V/		$I_{OH} = -3 \text{ mA}$	1.1 V	0.8			V
VOH		$I_{OH} = -5 \text{ mA}$	1.4 V	1			V
		$I_{OH} = -8 \text{ mA}$	1.65 V	1.2			
		$I_{OH} = -9 \text{ mA}$	2.3 V	1.8			
		I <sub>OL</sub> = 100 μA	0.8 V to 2.7 V			0.2	
		I <sub>OL</sub> = 0.7 mA	0.8 V		0.25		
V/0:		I <sub>OL</sub> = 3 mA	1.1 V			0.3	V
VOL		I <sub>OL</sub> = 5 mA	1.4 V			0.4	V
		I <sub>OL</sub> = 8 mA	1.65 V			0.45	
		I <sub>OL</sub> = 9 mA	2.3 V			0.6	
II	A or B input	$V_I = V_{CC}$ or GND	0 to 2.7 V			±5	μΑ
l <sub>off</sub>		$V_I$ or $V_O = 2.7 V$	0			±10	μΑ
ICC		$V_I = V_{CC}$ or GND, $I_O = 0$	0.8 V to 2.7 V			10	μΑ
Ci		$V_I = V_{CC}$ or GND	2.5 V		3		pF

<sup>†</sup> All typical values are at  $T_A = 25$ °C.



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# switching characteristics over recommended operating free-air temperature range, $C_L$ = 15 pF (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = 0.8 V	0.8 V V <sub>CC</sub> = 1.2 V ± 0.1 V		V <sub>CC</sub> = 1.5 V ± 0.1 V		V <sub>CC</sub> = 1.8 V ± 0.15 V		V <sub>CC</sub> = 2.5 V ± 0.2 V		UNIT	
	(1141 01)	(0011 01)	TYP	MIN	MAX	MIN	MAX	MIN	TYP	MAX	MIN	MAX	
t <sub>pd</sub>	A or B	Y	4.7	0.9	3.3	0.6	2.3	†	†	†	†	†	ns

<sup>†</sup> This information was not available at the time of publication.

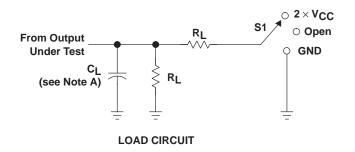
# switching characteristics over recommended operating free-air temperature range, $C_L$ = 30 pF (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = 1.8 V ± 0.15 V			V <sub>CC</sub> = 2.5 V ± 0.2 V		UNIT
		(0011 01)	MIN	TYP	MAX	MIN	MAX	
<sup>t</sup> pd	A or B	Υ	0.7	1.3	2.4	0.5	2	ns

## operating characteristics, $T_A = 25^{\circ}C$

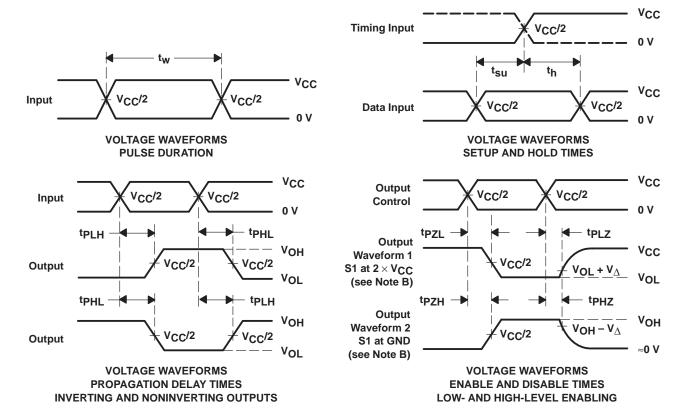
	PARAMETER	TEST CONDITIONS	V <sub>CC</sub> = 0.8 V	V <sub>CC</sub> = 1.2 V	V <sub>CC</sub> = 1.5 V	V <sub>CC</sub> = 1.8 V	V <sub>CC</sub> = 2.5 V	UNIT
	Power dissipation							
C <sub>pd</sub>	capacitance	f = 10 MHz	15	15	15	15	19	pF

#### PARAMETER MEASUREMENT INFORMATION



TEST	S1
tPLH/tPHL	Open
tPLZ/tPZL	$2 \times \mathbf{V_{CC}}$
tPHZ/tPZH	GND

VCC	CL	RL	$v_{\scriptscriptstyle\Delta}$
0.8 V	15 pF	<b>2 k</b> Ω	0.1 V
1.2 V $\pm$ 0.1 V	15 pF	<b>2 k</b> Ω	0.1 V
1.5 V $\pm$ 0.1 V	15 pF	<b>2 k</b> Ω	0.1 V
1.8 V $\pm$ 0.15 V	15 pF	<b>2 k</b> Ω	0.15 V
2.5 V $\pm$ 0.2 V	15 pF	<b>2 k</b> Ω	0.15 V
1.8 V $\pm$ 0.15 V	30 pF	<b>1 k</b> Ω	0.15 V
2.5 V $\pm$ 0.2 V	30 pF	500 Ω	0.15 V



NOTES: A.  $C_L$  includes probe and jig capacitance.

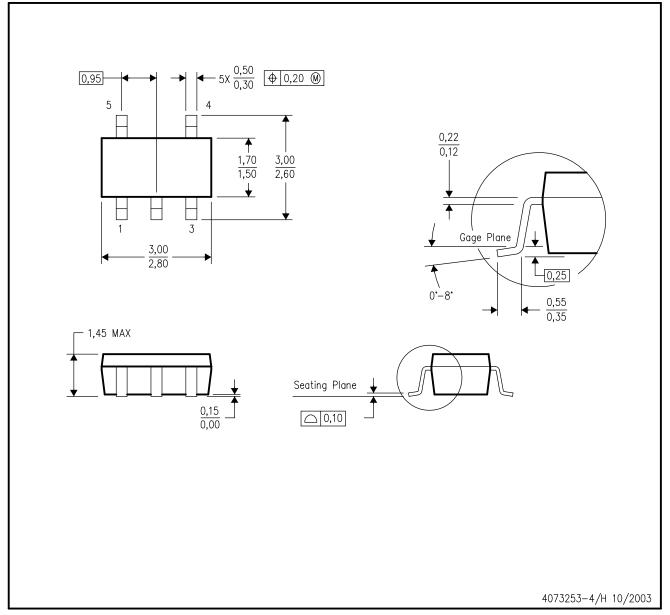
- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50 \Omega$ , slew rate  $\geq$  1 V/ns.
- D. The outputs are measured one at a time with one transition per measurement.
- E. tpLZ and tpHZ are the same as tdis.
- F. tpzL and tpzH are the same as ten.
- G. tpLH and tpHL are the same as tpd.
- H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms



# DBV (R-PDSO-G5)

## PLASTIC SMALL-OUTLINE PACKAGE



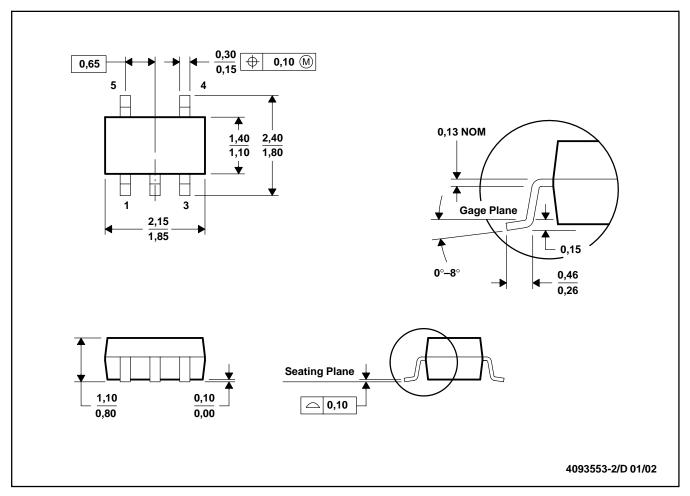
NOTES:

- All linear dimensions are in millimeters.
- This drawing is subject to change without notice.
- C. Body dimensions do not include mold fla D. Falls within JEDEC MO—178 Variation AA. Body dimensions do not include mold flash or protrusion.



#### DCK (R-PDSO-G5)

#### PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

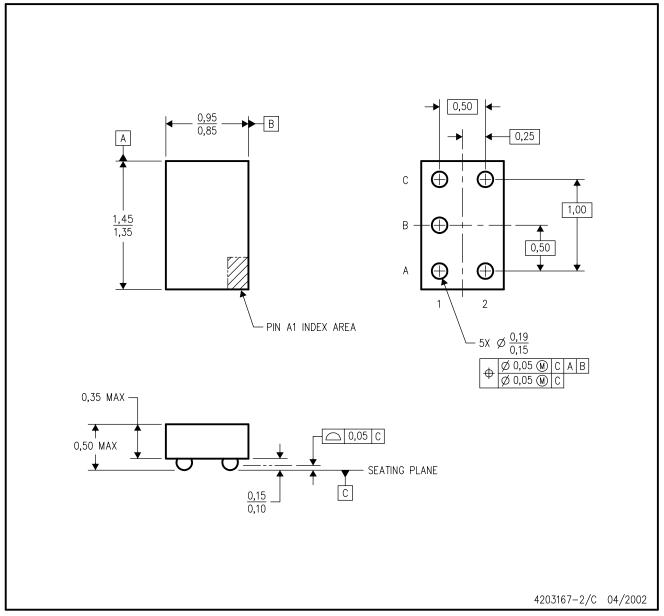
B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion.

D. Falls within JEDEC MO-203

# YEA (R-XBGA-N5)

## DIE-SIZE BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters.

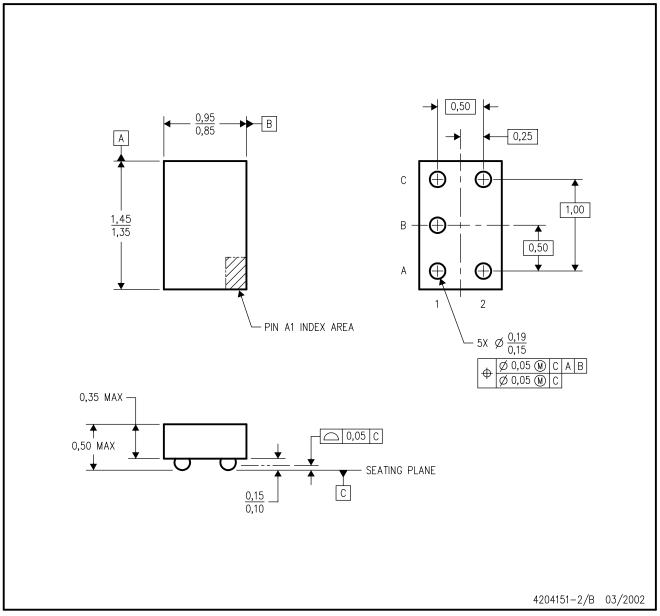
- B. This drawing is subject to change without notice.
- C. NanoStar  $\mathbf{M}$  package configuration.
- D. Package complies to JEDEC MO-211 variation EA.
- E. This package is tin-lead (SnPb). Refer to the 5 YZA package (drawing 4204151) for lead-free.

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# YZA (R-XBGA-N5)

## DIE-SIZE BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters.

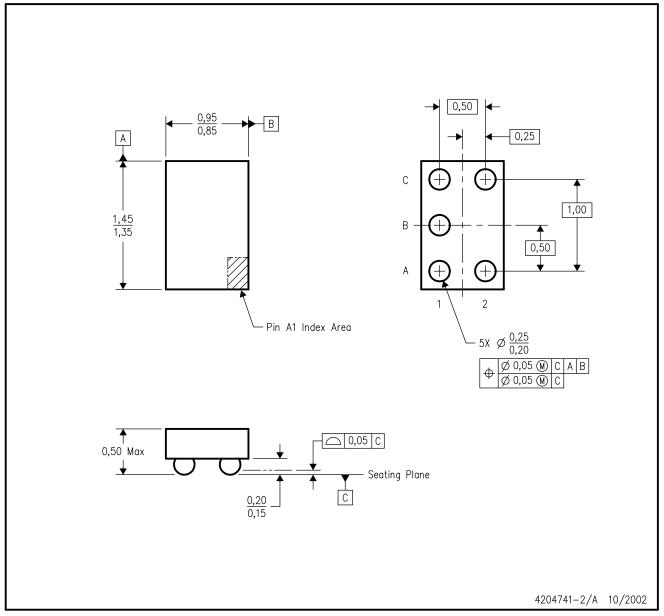
- B. This drawing is subject to change without notice.
- C. NanoFree  $^{\text{TM}}$  package configuration.
- D. Package complies to JEDEC MO-211 variation EA.
- E. This package is lead-free. Refer to the 5 YEA package (drawing 4203167) for tin-lead (SnPb).

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# YZP (R-XBGA-N5)

## DIE-SIZE BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters.

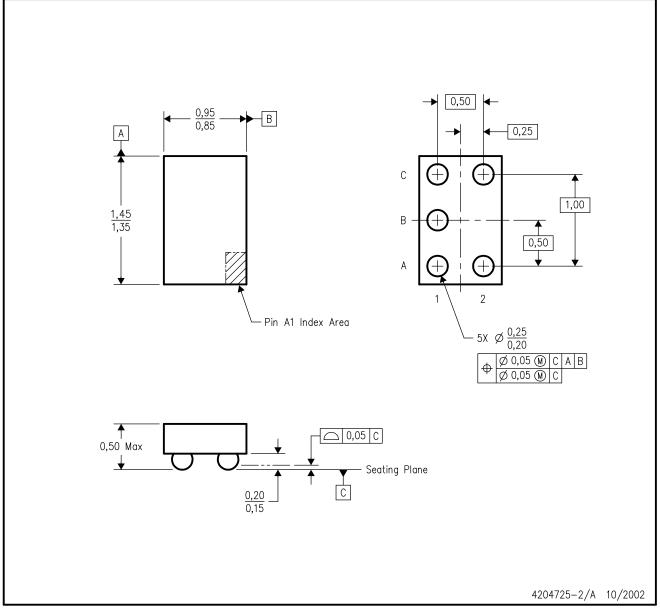
- B. This drawing is subject to change without notice.
- C. NanoFree  $^{\text{TM}}$  package configuration.
- D. This package is lead-free. Refer to the 5 YEP package (drawing 4204725) for tin-lead (SnPb).

NanoFree is a trademark of Texas Instruments.



# YEP (R-XBGA-N5)

## DIE-SIZE BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. NanoStar  $\mathbf{M}$  package configuration.
- D. This package is tin-lead (SnPb). Refer to the 5 YZP package (drawing 4204741) for lead-free.

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Mailing Address: Texas Instruments

Post Office Box 655303 Dallas, Texas 75265

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